

## HiPerFRED<sup>2</sup>

**V<sub>RRM</sub>** = 200 V  
**I<sub>FAV</sub>** = 2x 10 A  
**t<sub>rr</sub>** = 35 ns

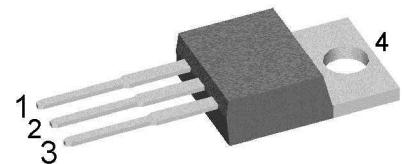
High Performance Fast Recovery Diode

Low Loss and Soft Recovery

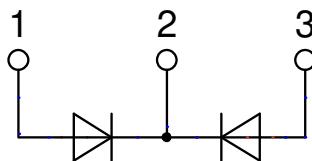
Common Cathode

Part number

**DPG20C200PB**



Backside: cathode



### Features / Advantages:

- Planar passivated chips
- Very low leakage current
- Very short recovery time
- Improved thermal behaviour
- Very low I<sub>rm</sub>-values
- Very soft recovery behaviour
- Avalanche voltage rated for reliable operation
- Soft reverse recovery for low EMI/RFI
- Low I<sub>rm</sub> reduces:
  - Power dissipation within the diode
  - Turn-on loss in the commutating switch

### Applications:

- Antiparallel diode for high frequency switching devices
- Antisaturation diode
- Snubber diode
- Free wheeling diode
- Rectifiers in switch mode power supplies (SMPS)
- Uninterruptible power supplies (UPS)

### Package: TO-220

- Industry standard outline
- RoHS compliant
- Epoxy meets UL 94V-0

### Disclaimer Notice

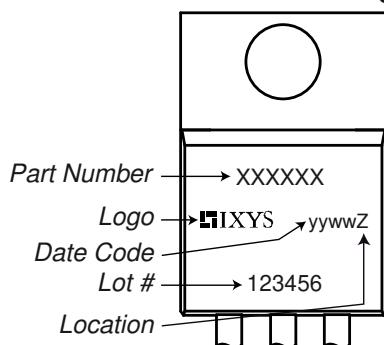
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**Fast Diode**

Symbol	Definition	Conditions	Ratings			
			min.	typ.	max.	
$V_{RSM}$	max. non-repetitive reverse blocking voltage	$T_{VJ} = 25^\circ\text{C}$			200	V
$V_{RRM}$	max. repetitive reverse blocking voltage	$T_{VJ} = 25^\circ\text{C}$			200	V
$I_R$	reverse current, drain current	$V_R = 200 \text{ V}$ $V_R = 200 \text{ V}$	$T_{VJ} = 25^\circ\text{C}$ $T_{VJ} = 150^\circ\text{C}$		1 0.06	$\mu\text{A}$ mA
$V_F$	forward voltage drop	$I_F = 10 \text{ A}$ $I_F = 20 \text{ A}$ $I_F = 10 \text{ A}$ $I_F = 20 \text{ A}$	$T_{VJ} = 25^\circ\text{C}$ $T_{VJ} = 150^\circ\text{C}$		1.27 1.45 0.98 1.17	V V V V
$I_{FAV}$	average forward current	$T_C = 150^\circ\text{C}$ rectangular $d = 0.5$	$T_{VJ} = 175^\circ\text{C}$		10	A
$V_{F0}$ $r_F$	threshold voltage slope resistance } for power loss calculation only		$T_{VJ} = 175^\circ\text{C}$		0.74 17.7	V $\text{m}\Omega$
$R_{thJC}$	thermal resistance junction to case				2.3	K/W
$R_{thCH}$	thermal resistance case to heatsink			0.5		K/W
$P_{tot}$	total power dissipation		$T_C = 25^\circ\text{C}$		65	W
$I_{FSM}$	max. forward surge current	$t = 10 \text{ ms}; (50 \text{ Hz}), \text{sine}; V_R = 0 \text{ V}$	$T_{VJ} = 45^\circ\text{C}$		140	A
$C_J$	junction capacitance	$V_R = 150 \text{ V}$ $f = 1 \text{ MHz}$	$T_{VJ} = 25^\circ\text{C}$	15		pF
$I_{RM}$	max. reverse recovery current		$T_{VJ} = 25^\circ\text{C}$ $T_{VJ} = 125^\circ\text{C}$	3 5.5		A A
$t_{rr}$	reverse recovery time	$I_F = 10 \text{ A}; V_R = 130 \text{ V}$ $-di_F/dt = 200 \text{ A}/\mu\text{s}$	$T_{VJ} = 25^\circ\text{C}$ $T_{VJ} = 125^\circ\text{C}$	35 45		ns ns

**Package TO-220**

Symbol	Definition	Conditions	Ratings		
			min.	typ.	max.
$I_{RMS}$	RMS current	per terminal <sup>1)</sup>			35 A
$T_{VJ}$	virtual junction temperature		-55		175 °C
$T_{op}$	operation temperature		-55		150 °C
$T_{stg}$	storage temperature		-55		150 °C
<b>Weight</b>				2	g
$M_d$	mounting torque		0.4		0.6 Nm
$F_c$	mounting force with clip		20		60 N

**Product Marking**

**Part description**

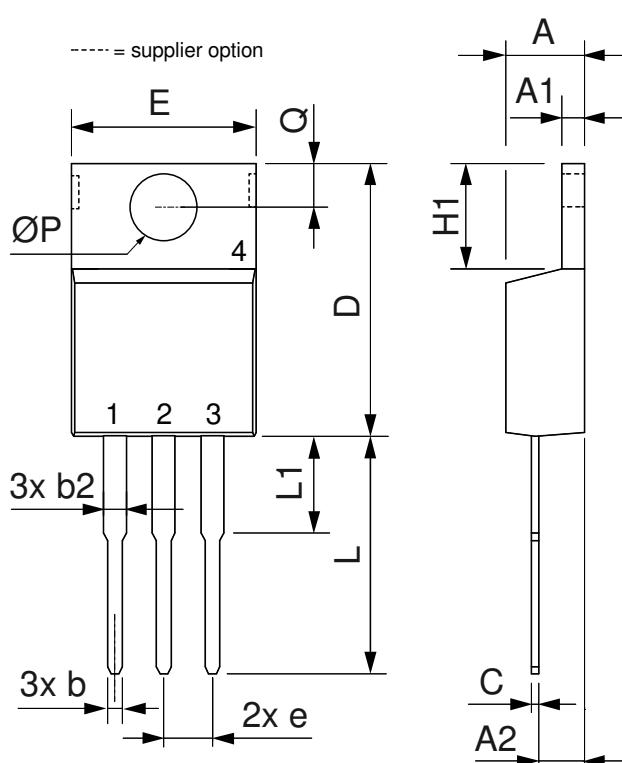
D = Diode  
 P = HiPerFRED  
 G = extreme fast  
 20 = Current Rating [A]  
 C = Common Cathode  
 200 = Reverse Voltage [V]  
 PB = TO-220AB (3)

Ordering	Ordering Number	Marking on Product	Delivery Mode	Quantity	Code No.
Standard	DPG20C200PB	DPG20C200PB	Tube	50	506308

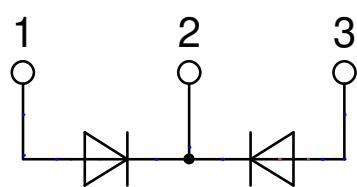
Similar Part	Package	Voltage class
DPG20C200PN	TO-220ABFP (3)	200

**Equivalent Circuits for Simulation**
*\* on die level*
 $T_{VJ} = 175^\circ\text{C}$ 

	<b>Fast Diode</b>	
$V_{0\ max}$	threshold voltage	0.74 V
$R_{0\ max}$	slope resistance *	14.5 mΩ

**Outlines TO-220**


Dim.	Millimeter		Inches	
	Min.	Max.	Min.	Max.
A	4.32	4.82	0.170	0.190
A1	1.14	1.39	0.045	0.055
A2	2.29	2.79	0.090	0.110
b	0.64	1.01	0.025	0.040
b2	1.15	1.65	0.045	0.065
C	0.35	0.56	0.014	0.022
D	14.73	16.00	0.580	0.630
E	9.91	10.66	0.390	0.420
e	2.54	BSC	0.100	BSC
H1	5.85	6.85	0.230	0.270
L	12.70	13.97	0.500	0.550
L1	2.79	5.84	0.110	0.230
ØP	3.54	4.08	0.139	0.161
Q	2.54	3.18	0.100	0.125



### Fast Diode

